# MN372132FT

# 4.5mm (type-1/4) CCD Area Image Sensor

### ■ Overview

The MN372132FT is a 4.5mm (type-1/4) interline transfer CCD (IT-CCD) solid state image sensor device.

This device uses photodiodes in the optoelectric conversion section and CCDs for signal read out. The electronic shutter function has made an exposure time of 1/10000 seconds possible. Further, this device has the features of high sensitivity, low noise, broad dynamic range, and low smear.

This device has a total of 320,589 pixels (537 horizontal × 597 vertical) and provides stable and clear images with a resolution of 330 horizontal TV-lines and 420 vertical TV-lines.

Part Number	Size	System	Color or B/W		
MN372132FT	4.5mm(type-1/4)	PAL	Color		

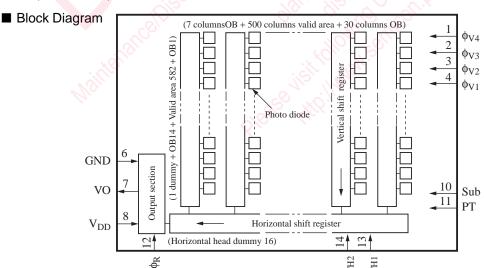
# Product internal inte

### ■ Features

- High sensitivity, Low noise, Broad dynamic range
- Low smear, Low image lag, Electronic shutter function present
- No image distortion
- Small size enables design of compact equipment
- High reliability, 14-pin plastic package

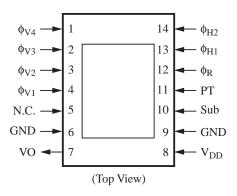
### Applications

 Compact lightweight camcorders. Cameras for surveillance, measurement, and medical use



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# ■ Pin Assignments



## ■ Pin Descriptions

Pin No.	Symbol	Descriptions	Pin No.	Symbol	Descriptions
1	$\phi_{\mathrm{V4}}$	Vertical shift register	6	GND	GND
		clock pulse 4	7	VO	Video output
2	φ <sub>V3</sub>	Vertical shift register	8	V <sub>DD</sub>	Power supply
		clock pulse 3	9	GND	GND
3	φ <sub>V2</sub>	Vertical shift register	10	Sub	Substrate
		clock pulse 2	115	PT	P-well for protection circuit
4	φ <sub>V1</sub>	Vertical shift register	12	$\phi_R$	Reset pulse (RG)
		clock pulse 1	13	ф <sub>Н1</sub>	Horizontal register clock pulse 1
5	N.C.	N.C.	14	φ <sub>H2</sub>	Horizontal register clock pulse 2

### ■ Absolute Maximum Ratings and Operating Conditions

Parameter			Rating		Operating condition			
		Symbol	min	max	min	typ	max	Unit
Power supply voltage		V <sub>DD</sub>	- 0.2	18.0	14.5	15.0	15.5	V
Protection P-well voltage		V <sub>PT</sub> *2	- 10.0	0.2	- 8.3	- 8.0	- 7.7	V
GND		GND	Reference voltage		_	0	_	V
Reset	H-L	$V_{\phi R(H-L)}$	_	18.0	4.7	5.0	5.3	V
pulse voltage	Bias	$V_{\phi R(Bias)}$		Sup	plied interr	V		
Horizontal registe	er	$V_{\phi H1(H)}$	-	18.0	4.7	5.0	5.3	V
clock pulse voltag	ge 1	$V_{\phi H1(L)}$	-0.2		- 0.05	0	0.05	
Horizontal registe	er	$V_{\phi H2(H)}$		18.0	4.7	5.0	5.3	V
clock pulse voltage 2		V <sub>oH2(L)</sub>	- 0.2	_	- 0.05	0	0.05	
Vertical shift register		V <sub>\phiV1(H)</sub> *2		18.0	14.5	15.0	15.5	V
clock pulse voltage 1		V <sub>\(\phi\V_{1(M)}\)</sub> *2	_		- 0.05	0	0.05	
		V <sub>\phiV1(L)</sub> *2	- 9.0		- 8.3	- 8.0	- 7.7	
Vertical shift register		V <sub>\phi V2(M)</sub> *2		15.0	- 0.05	0	0.05	V
clock pulse voltage 2		V <sub>\phiV2(L)</sub> *2	- 9.0		- 8.3	- 8.0	- 7.7	
Vertical shift register clock pulse voltage 3		V <sub>φV3(H)</sub> *2		18.0	14.5	15.0	15.5	V
		V <sub>\phi V3(M)</sub> *2	_	THE STATE OF THE S	- 0.05	0	0.05	
		V <sub>\phiV3(L)</sub> *2	- 9.0	10-10	- 8.3	-8.0	- 7.7	
Vertical shift regi	ster	V <sub>\phiV4(M)</sub> *2	200	15.0	-0.05 0 0.05		V	
clock pulse voltag	clock pulse voltage 4		- 9.0	11,-10	- 8.3	-8.0	5 <b>-</b> 7.7	
Substrate voltage	$ \begin{array}{c c} \text{clock pulse voltage 4} & V_{\phi V4(L)}^{*2} \\ \hline \text{Substrate voltage} & V_{Sub}^{*1} \\ \hline & \Delta V_{Sub}^{*3} \\ \end{array} $		Supplied internally					V
			- 0.2	45.0	21.5	22.0	22.5	<u> </u>
Operating temper	rature	$T_{\mathrm{opr}}$	- 10	70		25	_	°C
Storage temperate	ure	$T_{ m stg}$	- 30	80		1.60.		°C

### Note)1. Standard light input defines

Standard light input is the one when the exposure is done at a lens aperture of F8, using a light source of 2856 K and 1050 nt, and placing a color temperature conversion filter LB-40 (HOYA) and an IR cutting filter CAW-500 (t = 2.5 mm) in the light path.

- 2.  $*1: V_{Sub}$  internal settings guarantee blooming at 400 times light input of the standard light input.
- 3. \*2:  $V_{PT}$  is set so that the following conditions are set for VL of the vertical shift clock.  $V_{PT} \le VL$
- 4. \*3: V<sub>Sub</sub> when using electronic shutter function



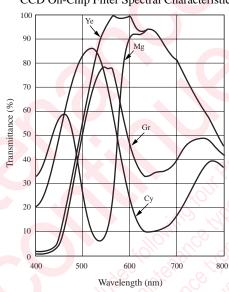
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## ■ Optical Characteristics

Part Number	Color or	Effe		S/N typ	Saturation output typ	Sensitivity F8 typ	Vertical smear Sm	Image lag typ	Horizontal resolution typ	Vertical resolution typ
	B/W	Н	V	(dB)	(mV)	(mV)	typ(%)	(%)	(TV-lines)	(TV-lines)
MN372132FT	Color	500	582	58	650	330	0.003		330	420

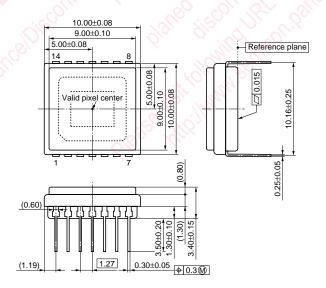
## ■ Graphs of Characteristics





# ■ Package Dimensions (Unit: mm)

• WDIP014-P-0400F



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